NSN 5961-01-174-1223

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-174-1223 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.107 inches **Function For Which Designed:** Varactor diode Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes forward current, average horsepower metric and 0.02 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 82.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release6283a professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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